

SLES226B-MAY 2008-REVISED FEBRUARY 2010

FM STEREO TRANSMITTER

Check for Samples: SN761634

FEATURES

- Single-Chip FM Stereo Transmitter
- Selectable I²C/Parallel Control Mode
- V_{CC} = 2.5 V to 4 V
- 76-MHz to 108-MHz Transmit Frequency Range
- Selectable –7-, –3-, 1-, 4-dBm Tx High-Power Output
- I_{CC} = 12 mA (Depends on Tx Power)
- 32.768-kHz Clock
- 24-Pin Quad Flatpack No Lead (QFN) Package, 4 × 4 mm
- Standby
- Fourth Order 15-kHz Low Pass Filter (LPF)

APPLICATIONS

- Portable Audio Players
- MP3 Players
- Personal Navigation Devices (PNDs)
- Portable Media Players (PMPs)

DESCRIPTION

The SN761634 is an FM stereo transmitter IC for portable audio players.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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www.ti.com **FM TRANSMITTER BLOCK** ADD_SEL(POW) PORT2 (D3) PORT1 (D2) vcc_osc GND_OSC BUS_SEL SCL (D1) SDA (D0) GND_RF GND_D GND_A D4 (D4) EMTC VCC TXPOW[1:0] LOGIC TXOUT LPF L IN Pre-+₽ -0 Emphasis osc MPX R_IN Pre-MODADJ[3:0] *# -0 Emphasis fc =15 kHz AFADJ[2:0] VT PLTADJ[2:0]

XTAL OSC

2

XTAL2

1

XTAL1

Texas

INSTRUMENTS

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	TERMINAL	DECODIDION	SOUTHATIC
NO.	NAME	DESCRIPTION	SCHEMATIC
1	D4(D4)	To be connected to ground in I ² C mode / D4 input in parallel mode	Figure 1
2	XTAL1	Crystal oscillator	Figure 2
3	XTAL2	Crystal oscillator	Figure 2
4	SDA(D0)	I2C data input/output in I ² C mode/ D0 input in parallel mode	Figure 3
5	SCL(D1)	I2C clock input / D1 input in parallel mode	Figure 4
6	PORT1(D2)	Port 1 output in I ² C mode / D2 input in parallel mode	Figure 5
7	PORT2(D3)	Port 2 output in I ² C mode / D3 input in parallel mode	Figure 5
8	EMTC	To be opened in I ² C mode / EMTC input in parallel mode	Figure 6
9	V _{CC}	Power supply	
10	GND_A	Analog ground	
11	R_IN	Audio right input	Figure 7
12	L_IN	Audio left input	Figure 7
13	ADD_SEL(POW)	I ² C address select in I ² C mode / TX power select in parallel mode	Figure 8
14	MPX_FIL	MPX PLL filter	Figure 9
15	GND_RF	RF ground	
16	IREF_FIL	Reference current filter	Figure 10
17	BUS_SEL	I ² C mode / Parallel mode select	Figure 11
18	TX_OUT	Transmitter output	Figure 12
19	V _{CC_OSC}	Oscillator power supply	
20	OSC	Oscillator input	Figure 13
21	VT	Tuning voltage output	Figure 14
22	GND_OSC	Oscillator ground	
23	CP	Charge pump output	Figure 14
24	GND_D	Digital ground	











Figure 2. XTAL1 and XTAL2



Figure 4. SCL(D1)





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Figure 5. PORT1(D2) and PORT2(D3)















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Figure 14. VT and CP



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage	V _{CC} , V _{CC_OSC}	-0.3	6.0	V
V _{IN}	Input voltage	Other pins	-0.3	V_{CC}	V
T _A	Operating free-air temperature range		-20	85	°C
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

			MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage	V _{CC} , V _{CC_OSC}	2.5	3	4	V
T _A	Operating free-air temperature		-20		85	°C



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



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ELECTRICAL CHARACTERISTICS

 $V_{CC} = 3 \text{ V}, T_A = 25^{\circ}\text{C}, \text{ RF} \text{ frequency } f_{RF} = 98.1 \text{ MHz}, \text{ BAND} = 0 \text{ (USEU)}, \text{ TXPOW}[1:0] = -7 \text{ dBm}, \text{ MODADJ}[3:0] = 5 \text{ dB} \text{ (for } 98.1 \text{ MHz}), \text{ audio signal frequency } f_{AF} = 1 \text{ kHz}, 100\% \text{ means FM } 75 \text{ kdev}, \text{ BW} = \text{LPF } 30 \text{ kHz}, \text{ measured with typical home hi-fi tuner. (unless otherwise noted)}$

Supply Voltages and Currents

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage	V_{CC} and V_{CC_OSC} are the same voltage	2.5	3	4	V
I _{CC TX1}	Tx mode supply current 1	No L_IN, R_IN input, TXPOW[1:0] = 00, R _{TX} = open		13		mA
I _{CC TX2}	Tx mode supply current 2	No L_IN, R_IN input, TXPOW[1:0] = 00, R _{TX} = open, DIS AFLPF = 1		12		mA
I _{CC TX3}	Tx mode supply current 3	No L_IN, R_IN input, TXPOW[1:0] = 10, R_{TX} = 300 Ω		18		mA
I _{CC TX4}	Tx mode supply current 4	No L_IN, R_IN input, TXPOW[1:0] = 11, R_{TX} = 150 Ω		24		mA
I _{CC STBY1}	Standby current 1	STBY bit = 1 in I^2C mode		0.1	10	μA
I _{CC STBY2}	Standby current 2	D4, D3, D2, D1, D0 = 0, 0, 0, 0, 0 in parallel mode		0.1	10	μA

Crystal Oscillator

	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
f _{XTAL}	Crystal oscillator frequency	Crystal $C_L = 12.5 \text{ pF}$		32.768		kHz

Voltage Controlled Oscillator

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{OSC}	Oscillator frequency range		150		217	MHz

Synthesizer

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Ν	Programmable counter	14 bit	271		16383	
f _{REF}	Reference frequency for phase detector			8.192		kHz
f _{STEP}	Tuning frequency step			8.192		kHz
ISTEP		CP[1:0] = 00		0.6		
	Charge pump current	CP[1:0] = 01		1.25		
ICP	Charge pump current	CP[1:0] = 10		2.5		μΑ
		CP[1:0] = 11		50		

RF Power

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
		TXPOW[1:0] = 00, R_{TX} = open, R_L = 50 Ω		-7				
V _{TXOUT}	TX output power	TXPOW[1:0] = 01, R_{TX} = 300 Ω, R_{L} = 50 Ω		-3		ID		
		TXPOW[1:0] = 10, R_{TX} = 300 Ω, R_{L} = 50 Ω		1		UDIII		
		TXPOW[1:0] = 11, R_{TX} = 150 Ω, R_L = 50 Ω		4				



AF Power

	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT	
		AFADJ [2:0] = 000		-9			
		AFADJ [2:0] = 001		—6			
		AFADJ [2:0] = 010		—3			
۸E		AFADJ [2:0] = 011 (Ref.)		0		dD	
AFADJ	AF input level aujust fatto	AFADJ [2:0] = 100		3		uБ	
		AFADJ [2:0] = 101		6			
		AFADJ [2:0] = 110		9			
		AFADJ [2:0] = 111		12			
V _{IMAX50}	AF maximum input level (pre-emphasis 50 μs)	AFADJ = 0 dB, EMTC = 0, f_s = 400 Hz, L = R each channel			1000	mVpp	
		AFADJ = 0 dB, EMTC = 0, $f_s = 10 \text{ kHz}$, L = R each channel			330	mVpp	
N	AF maximum input level	AFADJ = 0 dB, EMTC = 1, f_s = 400 Hz, L = R each channel			1000	mVpp	
VIMAX75	(pre-emphasis 75 μs)	AFADJ = 0 dB, EMTC = 1, $f_s = 10 \text{ kHz}$, L = R each channel			200	mVpp	
V _{IAF}	AF typical input level for 100% dev	AFADJ = 0 dB, f_s = 400 Hz, DIS_EM = 0, L = R each channel		250		mVrms	
f _{IAFR}	Input frequency range		20		15 k	Hz	
R _{IAF}	AF input impedance			40		kΩ	
t	Pro omphasis	EMTC bit = 0		50			
PRE	Pre-emphasis	EMTC bit = 1		75		μs	
f _{LPF}	AFLPF frequency response	DIS_AFLPF = 0, -3 dB		15		kHz	

Mono Mode

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
fo mono	Output frequency response	CP = 1.25 µA	20		15 k	Hz
S/N _{MONO98}	Mono S/N at 98.1 MHz (100% modulation)	$\label{eq:linear} \begin{array}{l} L = R = 250 \mbox{ mVrms}, \mbox{f}_{AF} = 1 \mbox{ kHz}, \mbox{ AFADJ} = 0 \mbox{ dB}, \\ \mbox{MODADJ} = 5 \mbox{ dB}, \mbox{ PLTADJ} = \mbox{off}, \mbox{ MONO}_ST = 1, \\ \mbox{RF} = 98.1 \mbox{ MHz}, \mbox{ BAND} = 0 \end{array}$		60		dB
THD _{MONO98}	Mono THD at 98.1 MHz (30% modulation)	L = R = 75 mVrms, f_{AF} = 1 kHz, AFADJ = 0 dB, MODADJ = 5 dB, PLTADJ = off, MONO_ST = 1, RF = 98.1 MHz, BAND = 0		0.5		%
S/N _{MONO83}	Mono S/N at 83 MHz (100% modulation)	L = R = 250 mVrms, f_{AF} = 1 kHz, AFADJ = 0 dB, MODADJ = 11 dB, PLTADJ = off, MONO_ST = 1, RF = 83.0 MHz, BAND = 1		60		dB
THD _{MONO83}	Mono THD at 83 MHz (30% modulation)	$\label{eq:linear} \begin{array}{l} L = R = 75 \text{ mVrms}, \ f_{AF} = 1 \text{ kHz}, \ AFADJ = 0 \text{ dB}, \\ MODADJ = 11 \text{ dB PLTADJ} = off, \ MONO_ST = 1, \\ RF = 83.0 \text{ MHz}, \ BAND = 1 \end{array}$		0.5		%
ATT _{MT MONO}	MUTE attenuation	MUTE bit = 1	50			dB

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	PARAMETER	TEST CONDITIONS	MIN	TYP	МАХ	UNIT
S/N _{ST98}	Stereo S/N at 98.1 MHz Main + sub = 90%, pilot = 10%	$ \begin{array}{l} L = R = 225 \text{ mVrms}, \ f_{AF} = 1 \text{ kHz}, \\ AFADJ = 0 \text{ dB}, \text{ MODADJ} = 5 \text{ dB}, \\ PLTADJ = 0 \text{ dB}, \ f_{RF} = 98.1 \text{ MHz}, \\ BAND = 0 \end{array} $		55		dB
SEP _{ST98}	Stereo separation at 98.1 MHz Main + sub = 30%, pilot = 10%	L or R = 75 mVrms, $f_{AF} = 1$ kHz, AFADJ = 0 dB, PLTADJ = 0 dB, MODADJ = 5 dB, $f_{RF} = 98.1$ MHz, BAND = 0		30		dB
THD _{ST98}	Stereo THD at 98.1 MHz Main + sub = 30%, pilot = 10%	L or R = 75 mVrms, $f_{AF} = 1$ kHz, AFADJ = 0 dB, PLTADJ = 0 dB, MODADJ = 5 dB, $f_{RF} = 98.1$ MHz, BAND = 0		1.0		%
S/N _{ST83}	Stereo S/N at 83.0 MHz Main + sub = 90%, pilot = 10%	L = R = 225 mVrms, f_{AF} = 1 kHz, AFADJ = 0 dB, PLTADJ = 0 dB, MODADJ = 11dB, f_{RF} = 83.0 MHz, BAND = 1		55		dB
SEP _{ST83}	Stereo separation at 83.0 MHz Main + sub = 30%, pilot = 10%	L or R = 75 mVrms, $f_{AF} = 1$ kHz, AFADJ = 0 dB, MODADJ = 11 dB, PLTADJ = 0 dB, $f_{RF} = 83.0$ MHz, BAND = 1		30		dB
THD _{ST83}	Stereo THD at 83.0 MHz Main + sub = 30%, pilot = 10%	L or R = 75 mVrms, $f_{AF} = 1$ kHz, AFADJ = 0 dB, MODADJ = 11 dB, PLTADJ = 0 dB, $f_{RF} = 83.0$ MHz, BAND = 1		1.0		%
DIFF _{ST MOD}	Left channel and right channel modulation difference	L = R = 75 mVrms, f_{AF} = 1 kHz, AFADJ = 0 dB, MODADJ = 11 dB, PLTADJ = 0 dB, f_{RF} = 98.1 MHz, BAND = 1 Lch level Ref.	-1		1	dB

Modulation

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		MODADJ[3:0] = 0000 (Ref.)		0		
		MODADJ[3:0] = 0001		1		
		MODADJ[3:0] = 0010		2		
		MODADJ[3:0] = 0011		3		
		MODADJ[3:0] = 0100		4		
		MODADJ[3:0] = 0101		5		
		MODADJ[3:0] = 0110		6		
MODD	Modulation adjust ratio	MODADJ[3:0] = 0111		7		dB
MODICADJ	Modulation adjust ratio	MODADJ[3:0] = 1000		8		uВ
		MODADJ[3:0] = 1001		9		
		MODADJ[3:0] = 1010		10		
		MODADJ[3:0] = 1011		11		
		MODADJ[3:0] = 1100		12		
		MODADJ[3:0] = 1101		13		
		MODADJ[3:0] = 1110		14		
		MODADJ[3:0] = 1111		15		
MOD _{MONO76}	TX mono modulation at 76.0 MHz	L = R = 250 mVrms, f_{AF} = 1 kHz, AFADJ = 0 dB, PLTADJ = off, MONO_ST = 1, MODADJ = 13 dB, BAND = 1		75		kHzdev
MOD _{MONO83}	TX mono modulation at 83.0 MHz	L = R = 250 mVrms, f_{AF} = 1 kHz, AFADJ = 0 dB, PLTADJ = off, MONO_ST = 1, MODADJ = 11 dB, BAND = 1		75		kHzdev
MOD _{MONO90}	TX mono modulation at 90.0 MHz	$\label{eq:L} \begin{array}{l} L = R = 250 \text{ mVrms}, \text{f}_{AF} = 1 \text{ kHz}, \\ \text{AFADJ} = 0 \text{ dB}, \text{PLTADJ} = \text{off}, \text{MONO}_\text{ST} = 1, \\ \text{MODADJ} = 8 \text{ dB}, \text{BAND} = 1 \end{array}$		75		kHzdev
MOD _{MONO87}	TX mono modulation at 87.5 MHz	$\label{eq:L} \begin{array}{l} L = R = 250 \ mVrms, \ f_{AF} = 1 \ kHz, \\ AFADJ = 0 \ dB, \ PLTADJ = off, \ MONO_ST = 1, \\ MODADJ = 9 \ dB, \ BAND = 0 \end{array}$		75		kHzdev



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Modulation (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
MOD _{MONO98}	TX mono modulation at 98.1 MHz	L = R = 250 mVrms, $f_{AF} = 1$ kHz, AFADJ = 0 dB, PLTADJ = off, MONO_ST = 1, MODADJ = 5 dB, BAND = 0		75		kHzdev
MOD _{MONO108}	TX mono modulation at 108.0 MHz		75		kHzdev	
		PLTADJ[2:0] = 000		-6		
		PLTADJ[2:0] = 001		-4		
		PLTADJ[2:0] = 010		-2		dB
MODR _{PLT}	Pilot modulation adjust ratio	PLTADJ[2:0] = 011 (Ref.)		0		
		PLTADJ[2:0] = 100		2		
		PLTADJ[2:0] = 101		4		
		PLTADJ[2:0] = 110		6		
MPLT _{TYP}	Typical pilot modulation	L = R = 225 mVrms, f_{AF} = 1 kHz, (main + sub = 90%), AFADJ = 0 dB, PLTADJ = 0 dB		10		%
	Minimum pilot modulation	L = R = 225 mVrms, f_{AF} = 1 kHz, (main + sub = 90%), AFADJ = 0 dB, PLTADJ = -6 dB		5		%
MPLT _{MAX}	Maximum pilot modulation	L = R = 225 mVrms, f_{AF} = 1 kHz, (main + sub = 90%), AFADJ = 0 dB, PLTADJ = 6 dB		20		%



I²C MODE (BUS_SEL PIN = GND)

	Table 1. Write Data												
BYTE	BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)					
Address	1	1	0	0	0	1	AS	0					
Data 1	MUTE	0	N13	N12	N11	N10	N9	N8					
Data 2	N7	N6	N5	N4	N3	N2	N1	N0					
Data 3	PLTADJ2	PLTADJ1	PLTADJ0	DIS_TX	MONO_ST	TXPOW1	TXPOW0	PORT1					
Data 4	PORT2	STBY	BAND	MODADJ3	MODADJ2	MODADJ1	MODADJ0	DIS_AFLPF					
Data 5	DIS_EM	EMTC	0	AFADJ2	AFADJ1	AFADJ0	CP1	CP0					
Data 6				(reserved	d) ⁽¹⁾								

I²C Write Data

(1) Do not write any data on reserved area. The data of this area is loaded at power-on reset.

Table 2. Write Data Symbol Description

SYMBOL			DEFAULT								
AS	Address select bit	0: ADD_SE 1: ADD_SE	L(POW) pin (L(POW) pin (GND Open		0					
MUTE	Mute control bit	0: Mute off 1: Mute on	0: Mute off 1: Mute on								
N13-N0	Programmable counter bits	Set main co	Set main counter								
PLTADJ2,	Pilot level adjust bits	PLTADJ2	PLTADJ1	PLTADJ0	Level	0,					
PLTADJ1, PLTADJ0		0	0	0	6 dB	1,					
TEIADoo		0	0	1	–4 dB	•					
		0	1	0	-2 dB						
		0	1	1	0 dB						
		1	0	0	2 dB						
		1	0	1	4 dB						
		1	1	0	6 dB						
		1	1	1	pilot off						
DIS_TX	Disable TX power amp bit	0: TX power 1: TX power	r amp on r amp off			0					
MONO_ST	Mono/stereo switch	0: 38 kHz si 1: 38 kHz si For mono m	ub carrier off ub carrier on ode, PLTAD	J bits have to	be set as "PLTADJ[2:0]=111"	0					
TXPOW1,	TX power level selection bits	TXPOW1	TXPOW0	Level		0,					
TXPOW0		0	0	–7 dBm		0					
		0	1	–3 dBm							
		1	0	1 dBm							
		1	1	4 dBm							
PORT1, PORT2	Port control bits	PORT1, PO 0: Low (Nch 1: High (Nch	RT2 are ena -MOS open o -MOS open	bled as gener drain on) drain off)	al purpose ports	1, 1					
STBY	Standby control bit	0: Standby of 1: Standby of 1:	off on			1					
BAND	Band selection bit	0: US/EU ba 1: Japan ba	and (87.5 MH nd (76 MHz 1	lz to 108 MHz to 90 MHz))	0					

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SYMBOL		DESCRIPTION								
MODADJ3-	Modulation adjust bits	MODADJ3	MODADJ2	MODADJ1	MODADJ0	Total Composite Level				
MODADJ0		0	0	0	0	0 dB				
		0	0	0	1	1 dB				
		0	0	1	0	2 dB				
		0	0	1	1	3 dB				
		0	1	0	0	4 dB				
		0	1	0	1	5 dB				
		0	1	1	0	6 dB				
		0	1	1	1	7 dB				
		1	0	0	0	8 dB				
		1	0	0	1	9 dB				
		1	0	1	0	10 dB				
		1	0	1	1	11 dB				
		1	1	0	0	12 dB				
		1	1	0	1	13 dB				
		1	1	1	0	14 dB				
		1	1	1	1	15 dB				
DIS_AFLPF	Disable 15 kHz LPF	0: AF 15-kHZ LPF enable 1: AF 15-kHZ LPF disable								
DIS_EM	Disable pre-emphasis bit	0: De-emph 1: De-emph	asis on asis off				0			
EMTC	Time constant control bit for pre-emphasis	0: 50 μs 1: 75 μs					1			
AFADJ2,	AF level adjust bits	AFDJ2	AFDJ1	AFDJ0	Level		0,			
AFADJ1,		0	0	0	–9 dB	-	1, 1			
AI AD30		0	0	1	-6 dB		1			
		0	1	0	–3 dB					
		0	1	1	0 dB					
		1	0	0	3 dB					
		1	0	1	6 dB					
		1	1	0	9 dB					
		1	1	1	12 dB					
CP1, CP0	CP current selection bits	CP1	CP0	CP Current			1, 0			
		0	0	0.6 μA						
		0	1	1.25 μA						
		1	0	2.5 μA						
		1	1	50 μA						

Table 2. Write Data Symbol Description (continued)



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PLL Setting in I²C Mode

Calculation of N13–N0 14-bit word (N_{PLL}) can be done as follows:

 f_{RF} = desired tuning frequency

 f_{XTAL} = crystal frequency (32.768 kHz)

$$N_{PLL} = 4 \times \frac{f_{RF}}{f_{XTAL}}$$

Example:

 $f_{RF} = 88.0 \text{ M}$

$$N_{PLL} = 4 \times \frac{88.0 \text{ M}}{32.768 \text{ kHz}} = 10742$$

The PLL word becomes 29F6h (N13, N12, N11, N10, N9, N8, N7, N6, N5, N4, N3, N2, N1, N0 = 10 1001 1111 0110).

Initial setting	Audio input level	L = R = 75 mVrms, AFADJ = 0 dB, f _s = 400 Hz								
	Pilot level:	PLTADJ = 0 dB means	10%							
	FM modulation:	MODADJ depends on T	X frequency to be 22.5 kHz dev.							
	Output power:	TXPOW = -7 dBm,	pullup resistance is not necessary							
		TXPOW = -3, 1 dBm,	antenna load 50 Ω add pullup resistance R_{TX} 300 Ω							
		TXPOW = 4 dBm,	antenna load 50 Ω add pullup resistance R_{TX} 150 Ω							

To Use External XTAL Signal

To use external signal instead of XTAL oscillation, pin assignment is as follows:

- XTAL1 (pin 9): OPEN
- XTAL2 (pin 10): signal input with coupling capacitor

Input signal wave should be sine wave or square wave, acceptable amplitude ranges are:

- Sine wave: 500 mVpp to 2 Vpp
- Rectangle (square) wave: 200 mVpp to 2 Vpp

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PARALLEL MODE (BUS_SEL PIN = OPEN)

Channel/Standby Setting in Parallel Mode

CHANNEL SETTING NO.	D4	D3	D2	D1	D0	FREQUENCY (MHz) OR STANDBY	MODADJ SETTING
0	0	0	0	0	0	standby	9
1	0	0	0	0	1	87.7	9
2	0	0	0	1	0	87.9	9
3	0	0	0	1	1	88.1	9
4	0	0	1	0	0	88.3	9
5	0	0	1	0	1	88.5	9
6	0	0	1	1	0	88.7	9
7	0	0	1	1	1	88.9	3
8	0	1	0	0	0	106.7	3
9	0	1	0	0	1	106.9	3
10	0	1	0	1	0	107.1	3
11	0	1	0	1	1	107.3	3
12	0	1	1	0	0	107.5	3
13	0	1	1	0	1	107.7	3
14	0	1	1	1	0	107.9	3
15	0	1	1	1	1	standby	3
16	1	0	0	0	0	standby	13
17	1	0	0	0	1	76.8	13
18	1	0	0	1	0	77.0	13
19	1	0	0	1	1	77.2	13
20	1	0	1	0	0	77.4	13
21	1	0	1	0	1	77.6	13
22	1	0	1	1	0	77.8	13
23	1	0	1	1	1	78.0	13
24	1	1	0	0	0	88.0	9
25	1	1	0	0	1	88.2	9
26	1	1	0	1	0	88.4	9
27	1	1	0	1	1	88.6	9
28	1	1	1	0	0	88.8	9
29	1	1	1	0	1	89.0	9
30	1	1	1	1	0	89.2	9
31	1	1	1	1	1	standby	9



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Table 3. TX Power Setting in Parallel Mode

ADD_SEL(POW) PIN	TX POWER
Open	4 dBm
330 k Ω ±20% pulldown	1 dBm
100 k Ω ±20% pulldown	–3 dBm
GND	–7 dBm

Table 4. Pre-Emphasis Setting in Parallel Mode

EMTC PIN	PRE-EMPHASIS TIME CONSTANT
Open	75 μs
GND	50 μs

Other settings used are "default" value in Table 1.

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A. Pin 1 (D4) input connects to GND.



NOTE

This application information is advisory and performance check is required at actual application circuits. TI assumes no responsibility for the consequences of use of this circuit, such as an infringement of intellectual property rights or other rights, including patents, of third parties.







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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Samples
	(1)		Drawing			(2)		(3)	(Requires Login)
SN761634RTWR	OBSOLETE	E WQFN	RTW	24		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nomina	al
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Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN761634RTWR	WQFN	RTW	24	0	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

3-Dec-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN761634RTWR	WQFN	RTW	24	0	367.0	367.0	35.0

MECHANICAL DATA



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 F. Falls within JEDEC M0-220.



<u>RTW (S-PWQFN-</u>N24)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTES: A. All linear dimensions are in millimeters



RTW (S-PWQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



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